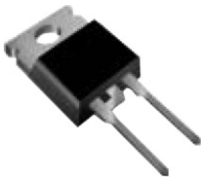
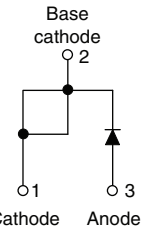
Schottky Rectifier, 20 A



TO-220AC



FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level

Pb-free Available

RoHS* COMPLIANT

DESCRIPTION

The 20TQ...PbF Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY	
$I_{F(AV)}$	20 A
V_R	35 to 45 V

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	20	A
V_{RRM}	Range	35 to 45	V
I_{FSM}	t_p = 5 µs sine	1800	A
V_F	20 Apk, T_J = 125 °C	0.51	V
T_J	Range	- 55 to 150	°C

VOLTAGE RATINGS					
PARAMETER	SYMBOL	20TQ035PbF	20TQ040PbF	20TQ045PbF	UNITS
Maximum DC reverse voltage	V_R	35	40	45	V
Maximum working peak reverse voltage	V_{RWM}				

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at T_C = 116 °C, rectangular waveform		20	A
Maximum peak one cycle non-repetitive surge current See fig. 7	I_{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	1800	
		10 ms sine or 6 ms rect. pulse		400	
Non-repetitive avalanche energy	E_{AS}	T_J = 25 °C, I_{AS} = 4 A, L = 3.4 mH		27	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		4	A

* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS					
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**VALUES**	**UNITS**
Maximum forward voltage drop See fig. 1	V_{FM} (1)	20 A	T_J = 25 °C	0.57	V
		40 A		0.73	
		20 A	T_J = 125 °C	0.51	
		40 A		0.67	
Maximum reverse leakage curent See fig. 2	I_{RM} (1)	T_J = 25 °C	V_R = Rated V_R	2.7	mA
		T_J = 125 °C		105	
Maximum junction capacitance	C_T	V_R = 5 V_{DC}, (test signal range 100 kHz to 1 MHz) 25 °C		1400	pF
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		**SYMBOL**	**TEST CONDITIONS**	**VALUES**	**UNITS**
Maximum junction and storage temperature range		T_J, T_{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation See fig. 4	1.50	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device				20TQ045	

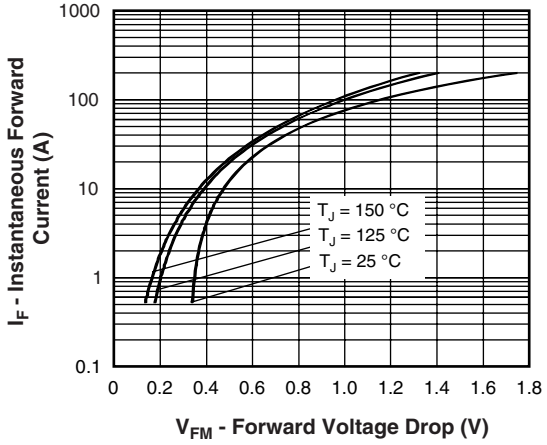


Fig. 1 - Maximum Forward Voltage Drop Characteristics

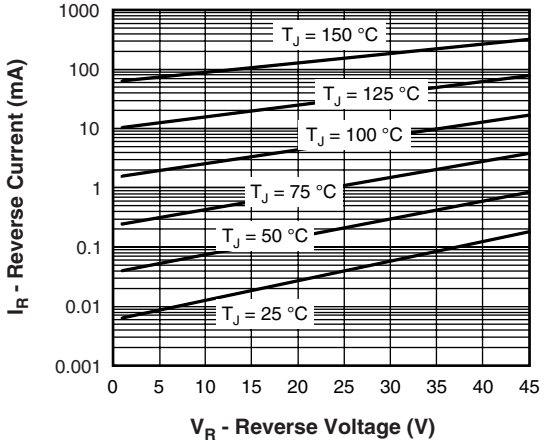


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

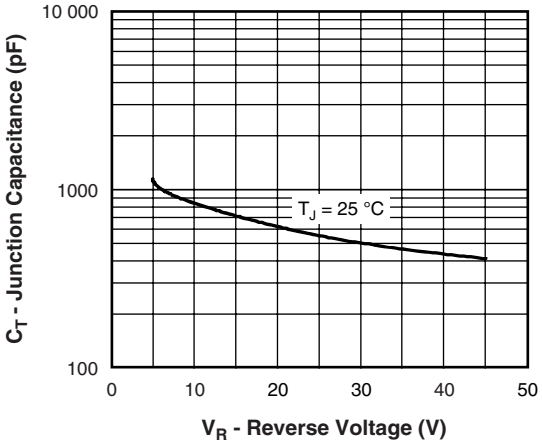


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

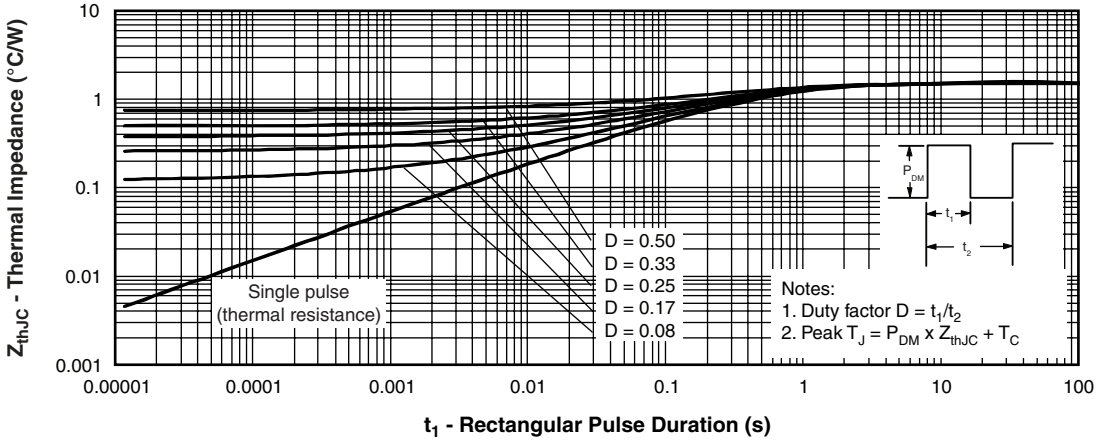


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

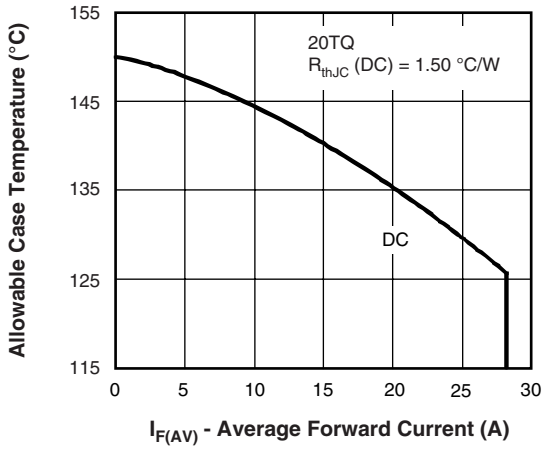


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

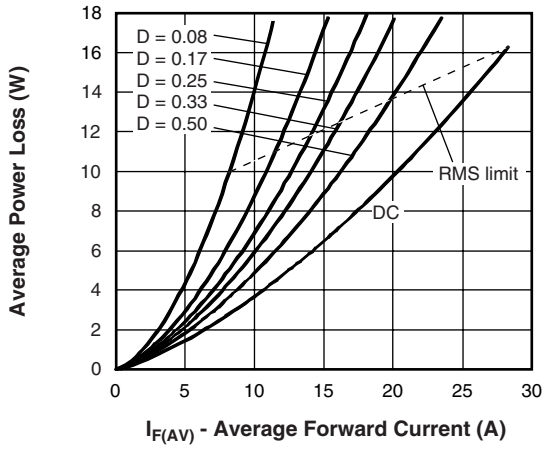


Fig. 6 - Forward Power Loss Characteristics

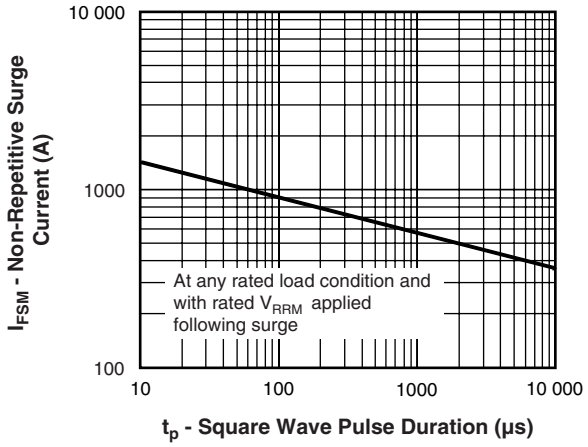


Fig. 7 - Maximum Non-Repetitive Surge Current

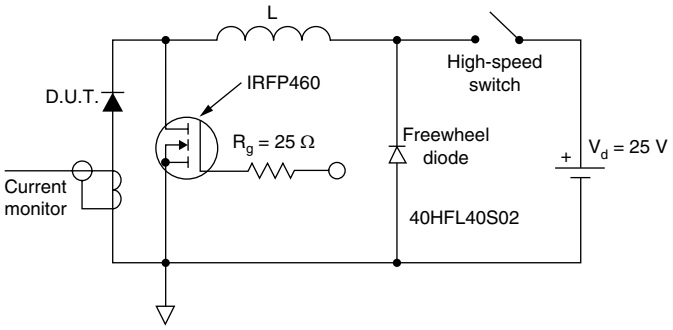
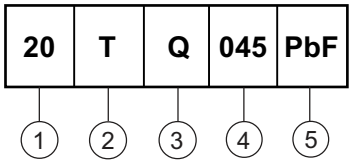


Fig. 8 - Unclamped Inductive Test Circuit

ORDERING INFORMATION TABLE

Device code



1 - Current rating (20 = 20 A)

2 - Package
T = TO-220

3 - Schottky “Q” series

4 - Voltage ratings
- 035 = 35 V
- 040 = 40 V
- 045 = 45 V

5 - • None = Standard production
• PbF = Lead (Pb)-free

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95221
Part marking information	http://www.vishay.com/doc?95216

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